

DMG3402L

N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D T _A = +25°C
	52mΩ @ V _{GS} = 10V	4A
30V	$65m\Omega$ @ $V_{GS} = 4.5V$	3A
	85mΩ @ V _{GS} = 2.5V	2A

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

Applications

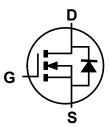
- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)

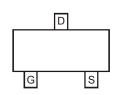


Top View



SOT23

Equivalent Circuit



Pin Configuration

Ordering Information (Note 4)

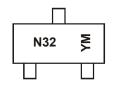
Part Number	Case	Packaging
DMG3402L-7	SOT23	3000/Tape & Reel
DMG3402L-13	SOT23	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



N32 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2012		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	Z		1	J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V _{DSS}	30	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 5)	I _D	4.0	Α
Body-Diode Continuous Current (Note 5)	Is	1.5	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	1.4	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	$R_{\theta JA}$	90	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C



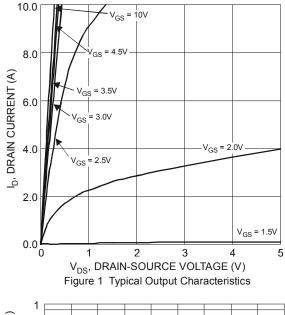
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

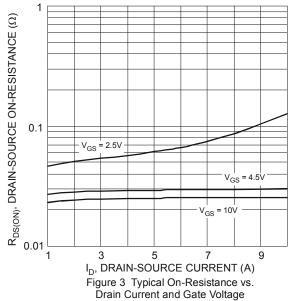
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 6)	OFF CHARACTERISTICS (Note 6)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$		
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	V _{DS} = 30V, V _{GS} = 0V		
Gate-Body Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 6)								
Gate Threshold Voltage	V _{GS(th)}	0.6	_	1.4	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$		
Static Drain-Source On-Resistance	R _{DS(on)}		_ _ _	52 65 85	mΩ	$V_{GS} = 10V, I_D = 4A$ $V_{GS} = 4.5V, I_D = 3A$ $V_{GS} = 2.5V, I_D = 2A$		
Forward Transconductance	Y _{fs}	_	6.6	_	S	$V_{DS} = 5V, I_D = 3.1A$		
Source-Drain Diode Forward Voltage	V_{SD}	_	_	1.16	V	$V_{GS} = 0V, I_S = 2.0A$		
DYNAMIC CHARACTERISTICS(Note 7)								
Gate Resistance	R _g	_	2.2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$		
Total Gate Charge (10V)	Qg	_	11.7	_	nC	V _{GS} = 10 V, V _{DS} = 15V, I _D = 4 A		
Total Gate Charge (4.5V)	Qg	_	5.5	_	nC	.,		
Gate-Source Charge	Qgs	_	1.1		nC	V _{GS} =10 V, V _{DS} = 15V, I _D = 4 A		
Gate-Drain Charge	Q_{gd}	_	1.8	_	nC	1D = 4 A		
Turn-On Delay Time	t _{D(on)}	_	1.9	_	ns			
Turn-On Rise Time	t _r	_	1.6		ns	V _{DD} = 15V, V _{GEN} = 10V,		
Turn-Off Delay Time	t _{D(off)}	_	10.3	_	ns	R_{GEN} =3 Ω , R_L = 3.75 Ω		
Turn-Off Fall Time	t _f	_	2.0	_	ns			
Input Capacitance	C _{iss}	_	464	_	pF			
Output Capacitance	Coss	_	49.5		pF	V _{DS} = 15V, V _{GS} = 0V f = 1.0MHz		
Reverse Transfer Capacitance	C _{rss}	_	43.8	_	pF	71 - 1.JIVII IZ		

Notes:

- 5. Device mounted on FR-4 PCB. $t \le 5$ sec.
- 6. Short duration pulse test used to minimize self-heating effect.
 7. Guaranteed by design. Not subject to production testing.







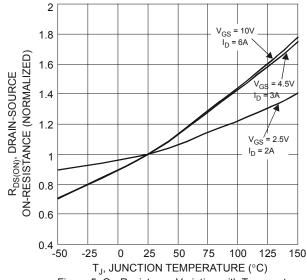
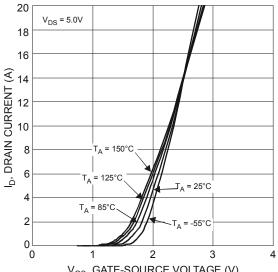
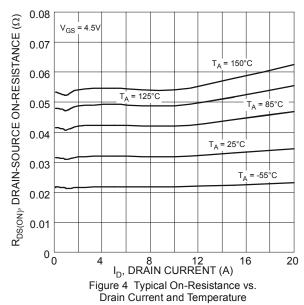


Figure 5 On-Resistance Variation with Temperature



 V_{GS} , GATE-SOURCE VOLTAGE (V) Figure 2 Typical Transfer Characteristics



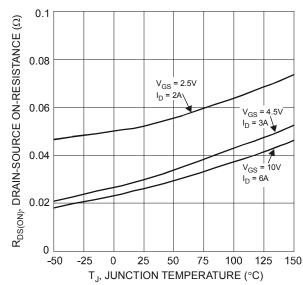


Figure 6 On-Resistance Variation with Temperature



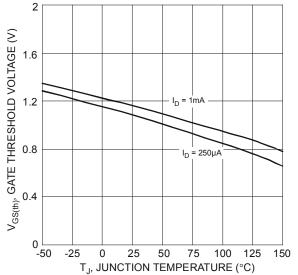
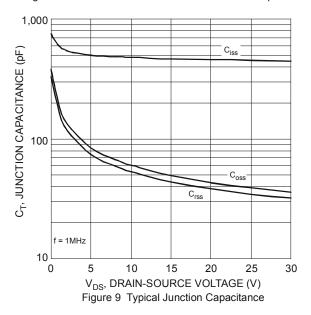
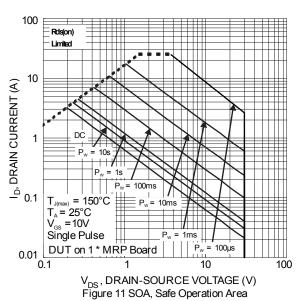
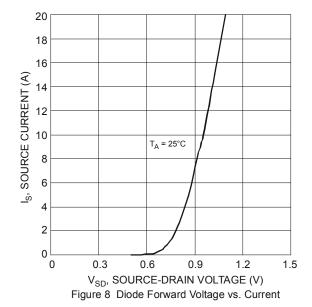
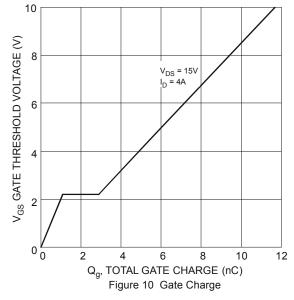


Figure 7 Gate Threshold Variation vs. Ambient Temperature

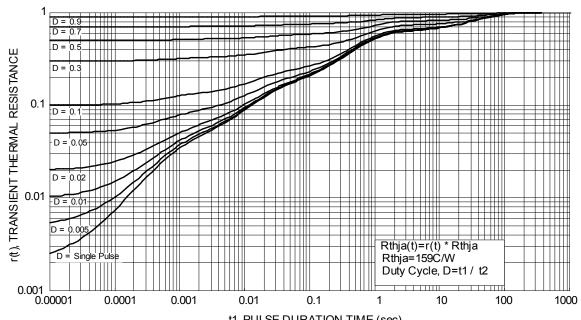












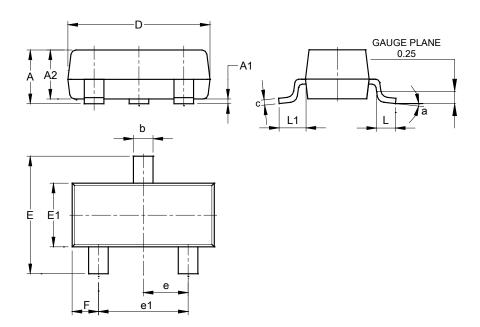
t1, PULSE DURATION TIME (sec) Figure 12 Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23 (Standard)

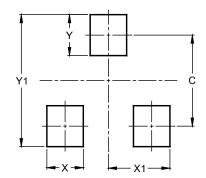


SOT23 (Standard)							
Dim	Min	Max	Тур				
Α	0.90	1.15	1.025				
A 1	0.00	0.10	0.05				
A2	0.85	1.10	0.975				
b	0.30	0.51	0.40				
С	0.080	0.202	0.11				
D	2.80	3.00	2.90				
Е	2.25	2.55	2.40				
E1	1.20	1.40	1.30				
е	0.89	1.03	0.915				
e1	1.78	2.05	1.83				
F	0.40	0.60	0.535				
L1	0.45	0.61	0.55				
L	0.25	0.55	0.40				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

 $Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

SOT23 (Standard)



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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